

MS1202

### **RF & MICROWAVE TRANSISTORS FM MOBILE APPLICATIONS**

#### Features

- 175 MHz
- 12.5 VOLTS
- **P**<sub>OUT</sub> = 7.0 W
- $G_P = 8.4 \text{ dB MINIMUM}$
- COMMON EMITTER CONFIGURATION



### DESCRIPTION:

The MS1202 is a epitaxial silicon NPN transistor designed for 12.5 volt class C applications in the 118 – 136 MHz frequency band and 28 volt FM ground station applications. Gold metalization and emitter ballast resistors provide long term product ruggedness and reliability.



### ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector - Base Voltage	65	V
V <sub>CEO</sub>	Collector - Emitter Voltage	35	V
V <sub>EBO</sub>	Emitter - Base Voltage	4.0	V
P <sub>DISS</sub>	Device Dissipation	15	W
TJ	Junction Temperature	200	°C
lc	Device Current	1.0	Α
T <sub>STG</sub>	Storage Temperature	-65 to +200	°C

#### Thermal Data

R <sub>TH(J-C)</sub> Thermal Resistance Junction-case	11.7	°C/W
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### ELECTRICAL SPECIFICATIONS (Tcase = 25°C)

STATIC

Symbol	Tost Conditions		Value			Unit	
	Test Conditions		Mi	n.	Тур.	Max.	Unit
BV <sub>ces</sub>	l <sub>c</sub> = 200 mA	V <sub>BE</sub> = 0 mA	6	5			V
BV <sub>ceo</sub>	l <sub>c</sub> = 200 mA	I <sub>B</sub> =0	3	5			V
BV <sub>ebo</sub>	l <sub>E</sub> = 5 mA	I <sub>c</sub> = 0 mA	4	ŀ			V
I <sub>cbo</sub>	V <sub>CB</sub> = 30 V	l <sub>E</sub> = 0 mA		-		1.0	mA
H <sub>FE</sub>	$V_{CE} = 5 V$	l <sub>c</sub> = 100 mA	5	5		150	

#### DYNAMIC

Symbol	Test Conditions	Value			Unit		
			Min.	Тур.	Max.	Unit	
Pout	f =175 MHz	V <sub>CE</sub> =28V		7.0			w
G <sub>P</sub>	f =175 MHz	V <sub>CE</sub> =28V		8.4			dB
η <sub>c</sub>	f =175 MHz	V <sub>CE</sub> =28V		60			%
Cob	f =1 MHz	V <sub>CE</sub> =30V				15	pF



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## PACKAGE MECHANICAL DATA



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